

SELECTED RECENT PUBLICATIONS:

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- *Structural, Mechanical, and Vibrational Properties of Ga_{1-x}In_xAs Alloy: A Molecular Dynamics Study*, P. S. Branicio, R. K. Kalia, A. Nakano, J. P. Rino, F. Shimojo, and P. Vashishta, *Appl. Phys. Lett.* **82**, 1057 (2003).
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